BAT42 BAT43

## SMALL SIGNAL SCHOTTKY DIODES

## DESCRIPTION

General purpose, metal to silicon diodes featuring very low turn-on voltage fast switching.
These devices have integrated protection against excessive voltage such as electrostatic dis-


ABSOLUTE RATINGS (limiting values)

| Symbol | Parameter | Value | Unit |  |
| :---: | :--- | :--- | :---: | :---: |
| $\mathrm{V}_{\text {RRM }}$ | Repetitive Peak Reverse Voltage | 30 | V |  |
| $\mathrm{I}_{\mathrm{F}}$ | Forward Continuous Current | $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ | 200 | mA |
| $\mathrm{I}_{\text {FRM }}$ | Repetitive Peak Fordware Current | $\mathrm{t}_{\mathrm{p}} \leq 1 \mathrm{~s}$ <br> $\delta \leq 0.5$ | 500 | mA |
| $\mathrm{I}_{\text {FSM }}$ | Surge non Repetitive Forward Current ${ }^{*}$ | $\mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}$ | 4 | A |
| $\mathrm{P}_{\text {tot }}$ | Power Dissipation* | $\mathrm{T}_{I}=65^{\circ} \mathrm{C}$ | 200 | mW |
| $\mathrm{T}_{\text {stg }}$ <br> $\mathrm{T}_{\mathrm{j}}$ | Storage and Junction Temperature Range | $-65 \mathrm{to}+150$ <br> $-65 \mathrm{to}^{\circ}+125$ | ${ }^{\circ} \mathrm{C}$ <br> ${ }^{\circ} \mathrm{C}$ |  |
| $\mathrm{T}_{\mathrm{L}}$ | Maximum Temperature for Soldering during 10 s at 4 mm from <br> Case | 230 | ${ }^{\circ} \mathrm{C}$ |  |

## THERMAL RESISTANCE

| Symbol | Test Conditions | Value | Unit |
| :---: | :---: | :---: | :---: |
| $\mathrm{R}_{\mathrm{th}(\mathrm{j}-\mathrm{a})}$ | Junction-ambient $^{*}$ | 300 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

* On infinite heatsink with 4 mm lead length


## ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

| Symbol | Test Conditions |  |  | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{B R}$ | $\mathrm{Tj}=25^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{R}}=100 \mu \mathrm{~A}$ |  | 30 |  |  | V |
| $\mathrm{VF}^{*}{ }^{\text {* }}$ | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{F}}=200 \mathrm{~mA}$ | All Types |  |  | 1 | V |
|  | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}$ | BAT 42 |  |  | 0.4 |  |
|  | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{F}}=50 \mathrm{~mA}$ |  |  |  | 0.65 |  |
|  | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{F}}=2 \mathrm{~mA}$ | BAT 43 | 0.26 |  | 0.33 |  |
|  | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ | $\mathrm{I}_{\mathrm{F}}=15 \mathrm{~mA}$ |  |  |  | 0.45 |  |
| $\mathrm{IR}^{*}$ | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ |  | $V_{R}=25 \mathrm{~V}$ |  |  | 0.5 | $\mu \mathrm{A}$ |
|  | $\mathrm{T}_{\mathrm{j}}=100^{\circ} \mathrm{E} C$ |  |  |  |  | 100 |  |

## DYNAMIC CHARACTERISTICS

| Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| C | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C} \quad \mathrm{V}_{\mathrm{R}}=1 \mathrm{~V} \quad \mathrm{f}=1 \mathrm{MHz}$ |  | 7 |  | pF |
| trr | $\begin{array}{ll} \begin{array}{l} \mathrm{Tj}=25^{\circ} \mathrm{C} \quad \mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA} \quad \mathrm{I}_{\mathrm{R}}=10 \mathrm{~mA} \\ \mathrm{R}_{\mathrm{L}}=100 \Omega \end{array} & \mathrm{i}_{\mathrm{rr}}=1 \mathrm{~mA} \\ \hline \end{array}$ |  |  | 5 | ns |
| h | $\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C} \quad \mathrm{R}_{\mathrm{L}}=15 \mathrm{~K} \Omega \quad \mathrm{C}_{\mathrm{L}}=300 \mathrm{pF} \quad \mathrm{f}=45 \mathrm{MHz} \quad \mathrm{V}_{\mathrm{i}}=2 \mathrm{~V}$ | 80 |  |  | \% |

* Pulse test: $\mathrm{t}_{\mathrm{p}} \leq 300 \mu \mathrm{~s} \quad \delta<2 \%$.

Fig. 1: Forward current versus forward voltage at different temperatures (typical values).


Fig. 2: Forward current versus forward voltage (typical values).


## PACKAGE MECHANICAL DATA

DO-35


Cooling method: by convection and conduction
Marking: clear, ring at cathode end.
Weight: 0.15 g

